

# FRED Pt® Ultrafast Soft Recovery Diode Module, 360 A



| PRODUCT SUMMARY           |                           |  |  |  |
|---------------------------|---------------------------|--|--|--|
| I <sub>F(AV)</sub>        | 360 A                     |  |  |  |
| $V_R$                     | 400 V                     |  |  |  |
| Q <sub>rr</sub> (typical) | 1250 nC                   |  |  |  |
| t <sub>rr</sub>           | 40 ns                     |  |  |  |
| Туре                      | Modules - Diode, FRED Pt® |  |  |  |

#### **FEATURES**

- Very low Q<sub>rr</sub> and t<sub>rr</sub>
- UL approved file E222165
- · Designed and qualified for industrial level
- Material categorization:
   For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>



#### RoHS COMPLIANT

#### **BENEFITS**

- Reduced RFI and EMI
- Higher frequency operation
- · Reduced snubbing

#### **DESCRIPTION**

FRED Pt® diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are a significant portion of the total losses.

| ABSOLUTE MAXIMUM RATINGS                    |                                   |                         |            |       |  |
|---|-----------------------------------|-------------------------|------------|-------|--|
| PARAMETER                                   | SYMBOL                            | TEST CONDITIONS         | MAX.       | UNITS |  |
| Cathode to anode voltage                    | $V_R$                             |                         | 400        | V     |  |
|   |                                   | T <sub>C</sub> = 25 °C  | 510        |       |  |
| Continuous forward current per diode        | I <sub>F(AV)</sub>                | T <sub>C</sub> = 85 °C  | 305        | А     |  |
|   |                                   | T <sub>C</sub> = 116 °C | 180        |       |  |
| Single pulse forward current per diode      | I <sub>FSM</sub>                  |                         | 1200       |       |  |
| Maximum power dissipation                   | $P_{D}$                           | T <sub>C</sub> = 25 °C  | 570        | W     |  |
|   |                                   | T <sub>C</sub> = 110 °C | 180        |       |  |
| Operating junction and storage temperatures | T <sub>J</sub> , T <sub>Stg</sub> |                         | -40 to 150 | °C    |  |

| <b>ELECTRICAL SPECIFICATIONS PER LEG</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                 |   |      |      |      |       |
|--|-----------------|---|------|------|------|-------|
| PARAMETER  | SYMBOL          | TEST CONDITIONS   | MIN. | TYP. | MAX. | UNITS |
| Breakdown voltage  | $V_{BR}$        | I <sub>R</sub> = 100 μA                                 | 400  | -    | -    |       |
|  |                 | I <sub>F</sub> = 180 A                                  | ı    | 1.09 | 1.27 |       |
| Famusard voltage   | V <sub>FM</sub> | I <sub>F</sub> = 360 A                                  | ı    | 1.23 | 1.50 | V     |
| Forward voltage  |                 | I <sub>F</sub> = 180 A, T <sub>J</sub> = 150 °C         | -    | 0.88 | 0.96 |       |
|  |                 | I <sub>F</sub> = 360 A, T <sub>J</sub> = 150 °C         | ı    | 1.04 | 1.18 |       |
| Reverse leakage current  | I <sub>RM</sub> | $T_J = 150  ^{\circ}\text{C},  V_R = V_R  \text{rated}$ | ı    | 0.26 | 1.28 | mA    |
| Series inductance  | L <sub>S</sub>  | From top of terminal hole to mounting plane             | -    | 5    | -    | nH    |



| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |  |   |  |        |      |      |       |
|---|--|---|--|--------|------|------|-------|
| PARAMETER   | SYMBOL   | TEST CONDITIONS   |  | MIN.   | TYP. | MAX. | UNITS |
|   |  | I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt = 200 A/μs, V <sub>R</sub> = 30 V                           |  | -      | 40   | 69   |       |
| Reverse recovery time t <sub>rr</sub>   | t <sub>rr</sub>  | T <sub>J</sub> = 25 °C  | I <sub>F</sub> = 180 A,<br>dI <sub>F</sub> /dt = 200 A/μs, | -      | 74   | i    | ns    |
|   |  | T <sub>J</sub> = 150 °C   | $V_{R} = 200 \text{ V}$                                    | -      | 171  | i    |       |
|   |  | $I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$                          |  | 1      | 5.1  | -    |       |
| Peak recovery current I <sub>RRM</sub>  | I <sub>RRM</sub>   | $I_F = 180 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 200 \text{ V}$                         |  | -      | 6.6  | -    | Α     |
|   | $I_F = 180 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A/}\mu\text{s}, \text{ V}_R = 200 \text{ V}, \text{ T}_J = 150 ^{\circ}\text{C}$ |   | -  | 15.2 - |      |      |       |
| Reverse recovery charge Q <sub>rr</sub>   |  | $I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$                          |  | -      | 125  | -    |       |
|   | $Q_{rr}$   | I <sub>F</sub> = 180 A, dI <sub>F</sub> /dt = 200 A/μs, V <sub>R</sub> = 200 V                          |  | -      | 243  | -    | nC    |
|   |  | I <sub>F</sub> = 180 A, dI <sub>F</sub> /dt = 200 A/µs, V <sub>R</sub> = 200 V, T <sub>J</sub> = 150 °C |  | -      | 1295 | -    |       |

| THERMAL - MECHANICAL SPECIFICATIONS             |               |                   |          |               |          |                     |
|---|---------------|-------------------|----------|---------------|----------|---------------------|
| PARAMETER                                       |               | SYMBOL            | MIN.     | TYP.          | MAX.     | UNITS               |
| Thermal resistance,                             | per leg       |                   | -        | -             | 0.19     |                     |
| junction to case                                | per<br>module | $R_{thJC}$        | -        | -             | 0.095    | °C/W                |
| Thermal resistance, case to heatsink (flag grea | sed surface)  | R <sub>thCS</sub> | -        | 0.10          | -        |                     |
| Weight  |               |                   | -        | 68            | -        | g                   |
|   |               |                   | -        | 2.4           | -        | oz.                 |
| Mounting torque                                 |               |                   | 30 (3.4) | -             | 40 (4.6) |                     |
| Mounting torque center hole                     |               |                   | 12 (1.4) | -             | 18 (2.1) | lbf · in<br>(N · m) |
| Terminal torque                                 | ninal torque  |                   | 30 (3.4) | -             | 40 (4.6) | (14 111)            |
| Vertical pull                                   |               |                   | -        | -             | 80       | - lbf ⋅ in          |
| 2" lever pull                                   | 2" lever pull |                   | -        | -             | 35       | - IDI · IN          |
| Case style                                      |               |                   |          | TO-244 (TO-24 | 44AB)    | •                   |

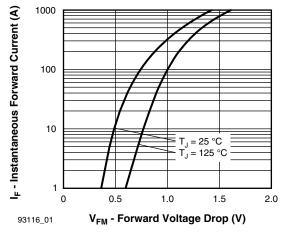


Fig. 1 - Typical Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

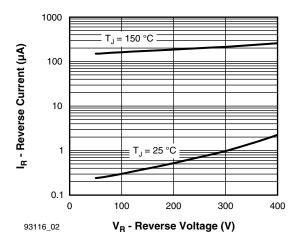


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

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## Vishay Semiconductors

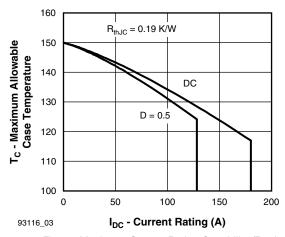


Fig. 3 - Maximum Current Rating Capability (Per Leg)

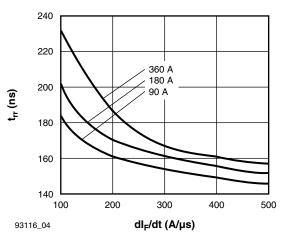


Fig. 4 - Typical Reverse Recovery Time vs.  $dI_F/dt$  $T_J = 125~^{\circ}C$  (Per Leg)

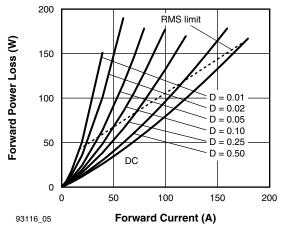


Fig. 5 - Forward Power Loss Characteristics

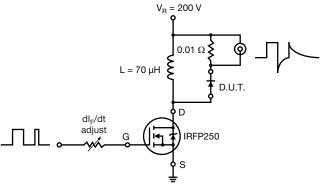
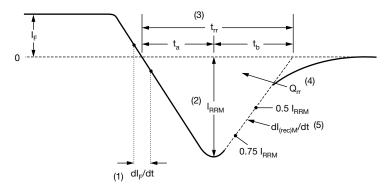


Fig. 6 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{\rm rr}$  area under curve defined by  $\mathbf{t}_{\rm rr}$  and  $\mathbf{I}_{\rm RRM}$

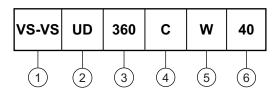
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 7 - Reverse Recovery Waveform and Definitions

#### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- 2 Type of device: UD = FRED Pt®
- 3 Current rating (360 = 360 A)
- 4 Circuit configuration:

C = Common cathode

5 - Type of device:

W = TO-244 wire bondable not isolated

6 - Voltage rating (40 = 400 V)

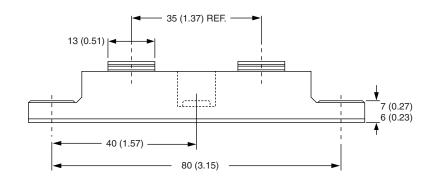
| CIRCUIT CONFIGURATION      |                               |   |  |  |
|----------------------------|-------------------------------|---|--|--|
| CIRCUIT                    | CIRCUIT<br>CONFIGURATION CODE | CIRCUIT DRAWING   |  |  |
| Two diodes common cathodes | С                             | Lug terminal o anode 2  Base common cathode  Lug terminal o anode 1 |  |  |

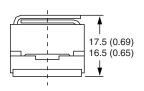
| LINKS TO RELATED DOCUMENTS |                          |  |  |
|----------------------------|--------------------------|--|--|
| Dimensions                 | www.vishay.com/doc?95021 |  |  |

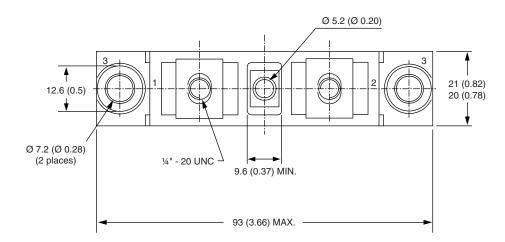


## **TO-244**

#### **DIMENSIONS** in millimeters (inches)









## **Legal Disclaimer Notice**

Vishay

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